

MEMC 99-1250/2441.1 PATENT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of Hariprasad Sreedharamurthy et al.

Art Unit 1765

Serial No. 10/039,459 Filed November 7, 2001 Confirmation No. 1061

APPARATUS AND PROCESS FOR THE PREPARATION OF LOW-IRON SINGLE CRYSTAL SILICON SUBSTANTIALLY FREE OF AGGLOMERATED INTRINSIC POINT DEFECTS

November 3, 2003

TO THE COMMISSIONER FOR PATENTS,

SIR:

<u>AMENDMENT B</u>

Amendments to the Drawings begin on page 2 of this paper and include an * enclosed replacement sheet and an annotated sheet showing changes.

Amendments to the Drawings

The enclosed replacement sheet includes a change to Figure 3. This sheet replaces the first formal drawing sheet that included Figure 3. During the preparation of the substitute formal drawing of Figure 3 (submitted on April 18, 2002), a triangle representing COATED - Y was not included for GRAPHITE GRADE C (as indicated in the annotated sheet). This triangle, however, was included in the original drawing of Figure 3 that was submitted when the application was filed (a copy of the original drawings is included herewith). As such, no new matter is being added by this amendment of Figure 3.

Enclosures: 1 Replacement Sheet

1 Annotated Sheet Showing Changes

1 original drawing

The Commissioner is hereby authorized to charge any additional fees which may be required to Deposit Account No. 19-1345.

Respectfully submitted,

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